

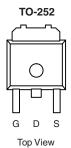
## 25N06L-TN3-VB Datasheet N-Channel 6 0-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$r_{DS(on)}$ ( $\Omega$ )	I <sub>D</sub> (A) <sup>a</sup>		
60	0.026 at V <sub>GS</sub> = 10 V	45		
	0.029 at V <sub>GS</sub> = 4.5 V	40		

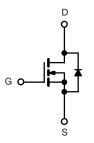
#### **FEATURES**

- TrenchFET® Power MOSFET
- 175 °C Junction Temperature





Drain Connected to Tab



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_C =$	25 °C, unless othe	rwise noted			
Parameter		Symbol	Limit	Unit	
Gate-Source Voltage		V <sub>GS</sub>	± 20	V	
Continuous Dunin Compant /T 475 90\h	T <sub>C</sub> = 25 °C	I-	40		
Continuous Drain Current (T <sub>J</sub> = 175 °C) <sup>b</sup>	T <sub>C</sub> = 100 °C	- I <sub>D</sub>	35		
Pulsed Drain Current		I <sub>DM</sub>	100	А	
Continuous Source Current (Diode Conduction)		I <sub>S</sub>	23		
Avalanche Current		I <sub>AS</sub>	20	1	
Single Avalanche Energy (Duty Cycle ≤ 1 %)	L = 0.1 mH	E <sub>AS</sub>	20	mJ	
Manianum Danian Disaination	T <sub>C</sub> = 25 °C	В	100	W	
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3 <sup>a</sup>	l vv	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a</sup>	t ≤ 10 sec	- R <sub>thJA</sub>	18	22	°C/W
Maximum Junction-to-Ambient	Steady State		40	50	
Maximum Junction-to-Case		R <sub>thJC</sub>	3.2	4	

#### Notes:

a. Surface Mounted on 1" x 1" FR4 board,  $t \le 10$  sec.

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• • •	T . O				SPECIFICATIONS $T_J = 25$ °C, unless otherwise noted       Parameter     Symbol     Test Conditions     Min     Typa     Max     Unit								
Symbol	Test Conditions	Min	Typ <sup>a</sup>	Max	Unit								
			1										
	40 / D 1	60			V								
V <sub>GS(th)</sub>		1.0	2.0	3.0									
I <sub>GSS</sub>	20 00			± 100	nA								
	50 00			1									
I <sub>DSS</sub>				50	μΑ								
	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$			250	1								
I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	50			Α								
	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 15 A		0.026										
r	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 15 A, T <sub>J</sub> = 125 °C		0.055										
r <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 15 A, T <sub>J</sub> = 175 °C		0.069		Ω								
	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 10 A		0.029										
9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 15 A		20		S								
C <sub>iss</sub>			1850		pF								
C <sub>oss</sub>	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		140										
C <sub>rss</sub>			60										
$Q_g$			11	17	nC								
Q <sub>gs</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 23 \text{ A}$		3										
$Q_{gd}$			3										
t <sub>d(on)</sub>			8	15									
t <sub>r</sub>	$V_{DD}$ = 30 V, $R_L$ = 1.3 $\Omega$ $I_D$ $\cong$ 23 A, $V_{GEN}$ = 10 V, $R_g$ = 2.5 $\Omega$		15	25	ns								
t <sub>d(off)</sub>			30	45									
t <sub>f</sub>			25	40									
racteristics	(T <sub>C</sub> = 25 °C)			l									
I <sub>SM</sub>				50	Α								
$V_{SD}$	I <sub>F</sub> = 15 A, V <sub>GS</sub> = 0 V		1.0	1.5	V								
t <sub>rr</sub>	I <sub>F</sub> = 15 A, di/dt = 100 A/μs		30	60	ns								
	$I_{DSS}$ $I_{D(on)}$ $I_{D(on)}$ $g_{fs}$ $C_{iss}$ $C_{oss}$ $C_{rss}$ $Q_{g}$ $Q_{gs}$ $Q_{gd}$ $t_{d(on)}$ $t_{r}$ $t_{d(off)}$ $t_{f}$ $aracteristics$ $I_{SM}$ $V_{SD}$	$\begin{array}{ c c c } \hline V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A} \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250 \mu\text{A} \\ \hline I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 20 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 125 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 175 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{DS} = 5 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 175 \text{ °C} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 175 \text{ °C} \\ \hline V_{GS} = 4.5 \text{ V, } I_D = 10 \text{ A} \\ \hline V_{DS} = 15 \text{ V, } I_D = 15 \text{ A} \\ \hline \hline C_{iss} & V_{GS} = 0 \text{ V, } V_{DS} = 25 \text{ V, } f = 1 \text{ MHz} \\ \hline \hline C_{rss} & V_{GS} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} \\ \hline \hline Q_{g} & V_{DS} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} \\ \hline Q_{gd} & t_{d(on)} & t_r & V_{DD} = 30 \text{ V, } R_L = 1.3 \Omega \\ \hline I_D \cong 23 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 2.5 \Omega \\ \hline \\ \text{aracteristics} & (T_C = 25 \text{ °C}) \\ \hline \hline I_{SM} & V_{SD} & I_F = 15 \text{ A, } V_{GS} = 0 \text{ V} \\ \hline \end{array}$	$\begin{array}{ c c c } \hline V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A} & 60 \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250 \mu\text{A} & 1.0 \\ \hline I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 20 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 125 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 175 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{DS} = 5 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 125 \text{ °C} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 175 \text{ °C} \\ \hline V_{GS} = 4.5 \text{ V, } I_D = 10 \text{ A} \\ \hline V_{DS} = 15 \text{ V, } I_D = 15 \text{ A} \\ \hline C_{ISS} \\ \hline C_{OSS} \\ \hline C_{OSS} \\ \hline C_{SS} \\ \hline C_{Qg} \\ \hline Q_{g} \\ \hline Q_{g} \\ \hline Q_{g} \\ \hline V_{DS} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} \\ \hline Q_{gd} \\ \hline t_{d(on)} \\ \hline t_r \\ \hline t_{d(off)} \\ \hline t_f \\ \hline \text{aracteristics} \\ \hline (T_C = 25 \text{ °C}) \\ \hline I_{SM} \\ \hline V_{SD} \\ \hline I_F = 15 \text{ A, } V_{GS} = 0 \text{ V} \\ \hline \end{array}$	$\begin{array}{ c c c c }\hline V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A} & 60 \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, \ I_D = 250 \mu\text{A} & 1.0 & 2.0 \\ \hline I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 20 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 125 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 175 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{DS} = 5 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{DS} = 15 \text{ V, } I_D = 10 \text{ A} \\ \hline V_{DS} = 15 \text{ V, } I_D = 15 \text{ A} \\ \hline C_{rss} \\ \hline C_{rss} \\ \hline C_{Oss} \\ \hline C_{gs} \\$	$\begin{array}{ c c c c c }\hline V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A} & 60 & \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250 \mu\text{A} & 1.0 & 2.0 & 3.0 \\ \hline I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 20 \text{ V} & \pm 100 \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} & 1 & \\ \hline I_{DSS} & V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} & 1 & \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 125 \text{ °C} & 50 \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 125 \text{ °C} & 250 \\ \hline I_{D(on)} & V_{DS} = 5 \text{ V, } V_{GS} = 10 \text{ V} & 50 & \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} & 0.026 & \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} & 0.026 & \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 125 \text{ °C} & 0.069 & \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 175 \text{ °C} & 0.069 & \\ \hline V_{GS} = 4.5 \text{ V, } I_D = 10 \text{ A} & 0.029 & \\ \hline V_{GS} = 4.5 \text{ V, } I_D = 15 \text{ A} & 20 & \\ \hline \hline \\ \hline C_{ISS} & V_{GS} = 0 \text{ V, } V_{DS} = 25 \text{ V, } f = 1 \text{ MHz} & 140 & \\ \hline \hline C_{TSS} & 60 & \\ \hline Q_g & 11 & 17 & \\ \hline Q_{gS} & V_{DS} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} & 3 & \\ \hline Q_{gd} & 3 & 11 & 17 & \\ \hline V_{DD} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} & 3 & \\ \hline I_D \cong 23 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 2.5 \Omega & 30 & 45 & \\ \hline I_f & 25 \text{ 40} & \\ \hline \\ \text{aracteristics} & (T_C = 25 \text{ °C}) & \\ \hline \\ \hline \\ \hline \\ \hline \end{array}$								

#### Notes:

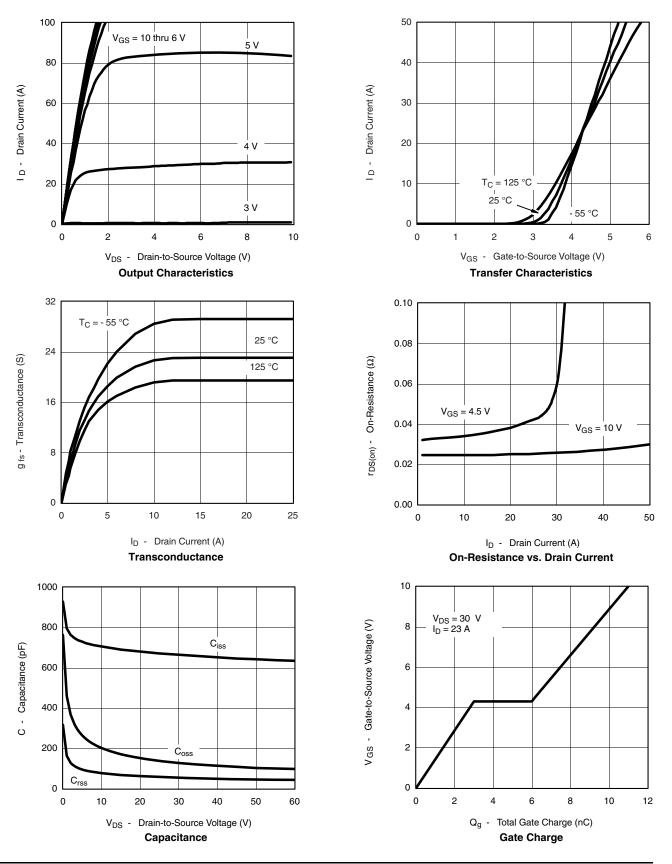
- a. For design aid only; not subject to production testing.
- b. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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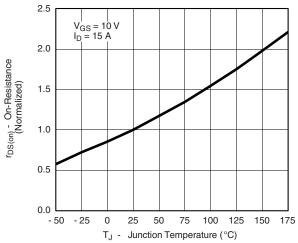


#### TYPICAL CHARACTERISTICS 25 °C unless noted

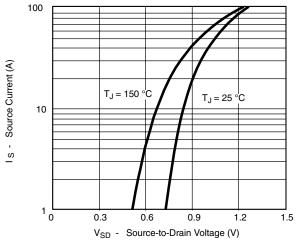




### TYPICAL CHARACTERISTICS 25 °C unless noted



On-Resistance vs. Junction Temperature

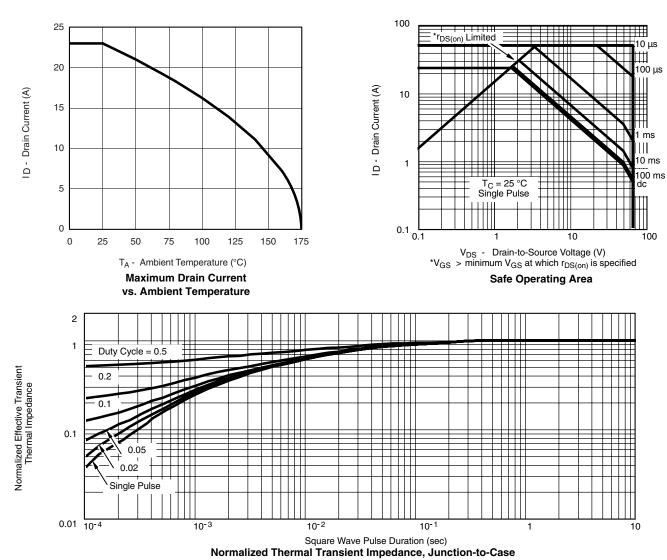


Source-Drain Diode Forward Voltage

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#### **THERMAL RATINGS**



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